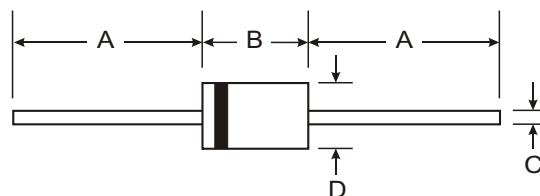
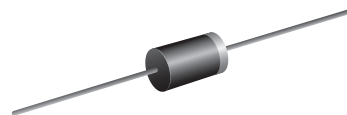




BYT13-600 - BYT13-1000

HIGH EFFICIENCY RECTIFIER DIODES

VOLTAGE RANGE: 600 - 1000V
CURRENT: 3.0 A



DO-201AD		
Dim	Min	Max
A	25.40	—
B	8.50	9.53
C	0.96	1.06
D	4.80	5.21
All Dimensions in mm		

Features

- Diffused Junction
- Low Forward Voltage Drop
- High Current Capability
- High Reliability
- High Surge Current Capability

Mechanical Data

- Case: DO-201AD, Molded Plastic
- Terminals: Plated Leads Solderable per MIL-STD-202, Method 208
- Polarity: Cathode Band
- Weight: 1.2 grams (approx.)
- Mounting Position: Any
- Marking: Type Number
- Epoxy: UL 94V-O rate flame retardant



Maximum Ratings and Electrical Characteristics T_A = 25°C unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic	Symbol	BYT13-600	BYT13-800	BYT13-1000	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	600	800	1000	V
RMS Reverse Voltage	V _{R(RMS)}	420	560	700	V
Average Rectified Output Current (Note 1) @ T _A = 55°C	I _O	3.0			A
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	I _{FSM}	150			A
Forward Voltage @ I _F = 3.0A	V _{FM}	1.3			V
Peak Reverse Current @ T _A = 25°C At Rated DC Blocking Voltage @ T _A = 100°C	I _{RM}	10.0 100			μA
Reverse Recovery Time (Note 2)	t _{rr}	50		75	nS
Typical Junction Capacitance (Note 3)	C _j	80		50	pF
Operating Temperature Range	T _j	-65 to +125			°C
Storage Temperature Range	T _{STG}	-65 to +150			°C

Note: 1. Leads maintained at ambient temperature at a distance of 9.5mm from the case

2. Measured with I_F = 0.5A, I_R = 1.0A, I_{RR} = 0.25A. See figure 5.

3. Measured at 1.0 MHz and applied reverse voltage of 4.0V D.C.

单击下面可查看定价，库存，交付和生命周期等信息

[>>SUNMATE\(森美特\)](#)